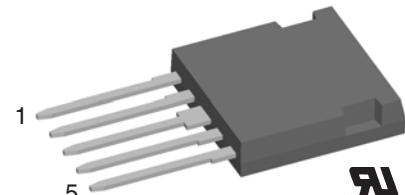
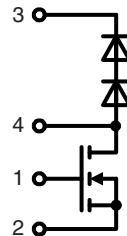


Q-Class Power MOSFETs

Chopper Topologies
in ISOPLUS i4-PAC™

Preliminary data

I_{D25} = 21 A
 V_{DSS} = 500 V
 $R_{DSon\ typ.}$ = 190 mΩ



MOSFET

Symbol	Conditions	Maximum Ratings		
V_{DSS}	$T_{VJ} = 25^\circ\text{C}$ to 150°C	500		V
V_{GS}		± 20		V
I_{D25}	$T_C = 25^\circ\text{C}$	21		A
I_{D90}	$T_C = 90^\circ\text{C}$	15		A

Symbol	Conditions	Characteristic Values		
		($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified)		
R_{DSon}	$V_{GS} = 10 \text{ V}; I_D = I_{D90}$		220	mΩ
V_{GSth}	$V_{DS} = 20 \text{ V}; I_D = 0.25 \text{ mA}$	2.5	4.5	V
I_{DSS}	$V_{DS} = V_{DSS}; V_{GS} = 0 \text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	250	250	μA
I_{GSS}	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0 \text{ V}$		200	nA
Q_g Q_{gs} Q_{gd}	$V_{GS} = 10 \text{ V}; V_{DS} = 0.5 \cdot V_{DSS}; I_D = 14 \text{ A}$	95 20 42		nC
$t_{d(on)}$ t_r $t_{d(off)}$ t_f	$V_{GS} = 10 \text{ V}; V_{DS} = 0.5 \cdot V_{DSS}$ $I_D = 14 \text{ A}; R_G = 2 \Omega$	20 20 50 15		ns
R_{thJC} R_{thJH}	with heat transfer paste	0.93	0.5	K/W

Features

- Q-Class Power MOSFET technology
 - low R_{DSon}
 - low gate charge for high frequency operation
 - unclamped inductive switching (UIS) capability
 - dv/dt ruggedness
- HiPerDyn™ FRED
 - consisting of series connected diodes
 - enhanced dynamic behaviour for high frequency operation
- ISOPLUS i4-PAC™ package
 - isolated back surface
 - UL registered E72873
 - low coupling capacity between pins and heatsink
 - enlarged creepage towards heatsink
 - application friendly pinout
 - low inductive current path
 - high reliability
 - industry standard outline

Applications

- chopper for power factor correction
- supply of high frequency transformer
 - switched mode power supplies
 - welding converters

Free Wheeling Diode (data for series connection)

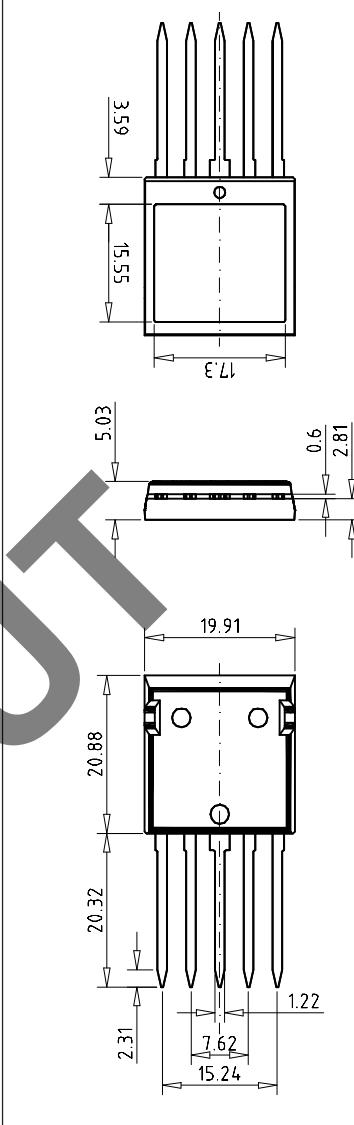
Symbol	Conditions	Maximum Ratings		
V_{RRM}	$T_{VJ} = 25^\circ\text{C}$ to 150°C	600		V
I_{F25}	$T_c = 25^\circ\text{C}$	60		A
I_{F90}	$T_c = 90^\circ\text{C}$	40		A

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
V_F	$I_F = 15 \text{ A}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	2.5 1.9	2.8 V	V
I_R	$V_R = V_{RRM}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	0.13	0.13 mA mA	
I_{RM} t_{rr}	$\left. \begin{array}{l} I_F = 30 \text{ A}; dI_F/dt = -500 \text{ A}/\mu\text{s}; T_{VJ} = 125^\circ\text{C} \\ V_R = 300 \text{ V} \end{array} \right\}$	9 40		A ns
R_{thJC} R_{thJH}	with heat transfer paste	1.3	0.65 K/W K/W	

Component

Symbol	Conditions	Maximum Ratings		
T_{VJ}		-55...+150		°C
T_{stg}		-55...+125		°C
V_{ISOL}	$I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}$	2500		V~
F_c	mounting force with clip	20...120		N

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
C_p	coupling capacity between shorted pins and mounting tab in the case	40		pF
d_s, d_A	pin - pin	1.7		mm
d_s, d_A	pin - backside metal	5.5		mm
Weight		9		g

Dimensions in mm (1 mm = 0.0394")

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